## BAV70LT1G, SBAV70LT1G, BAV70LT3G, SBAV70LT3G

# **Dual Switching Diode Common Cathode**

## **Features**

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

## **MAXIMUM RATINGS** (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	70	V
Forward Current	ΙF	200	mA
Peak Forward Surge Current	I <sub>FM(surge)</sub>	500	mA

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.

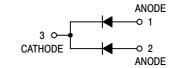


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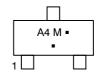
http://onsemi.com



SOT-23 (TO-236) CASE 318 STYLE 9



### **MARKING DIAGRAM**



A4 = Device Code
M = Date Code\*

• = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BAV70LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SBAV70LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BAV70LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SBAV70LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

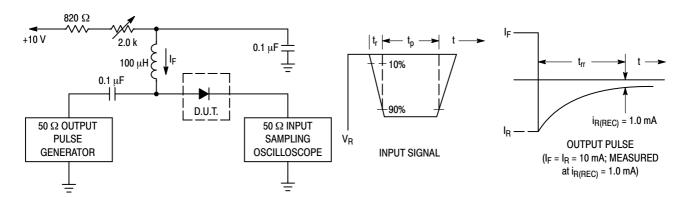
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## BAV70LT1G, SBAV70LT1G, BAV70LT3G, SBAV70LT3G

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Each Diode)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage $(I_{(BR)} = 100 \mu A)$	V <sub>(BR)</sub>	70	-	٧
Reverse Voltage Leakage Current (Note 3) $ (V_R = 25 \text{ V}, T_J = 150 ^{\circ}\text{C}) $ $ (V_R = 70 \text{ V}) $ $ (V_R = 70 \text{ V}, T_J = 150 ^{\circ}\text{C}) $	I <sub>R</sub>	- - -	60 2.5 100	μΑ
Diode Capacitance (V <sub>R</sub> = 0 V, f = 1.0 MHz)	C <sub>D</sub>	_	1.5	pF
Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$	V <sub>F</sub>	- - - -	715 855 1000 1250	mV
Reverse Recovery Time $R_L = 100 \Omega$ (I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>R(REC)</sub> = 1.0 mA) (Figure 1)	t <sub>rr</sub>	_	6.0	ns

<sup>3.</sup> For each individual diode while second diode is unbiased.



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (IF) of 10 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10 mA.
- 3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

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## **Curves Applicable to Each Anode**

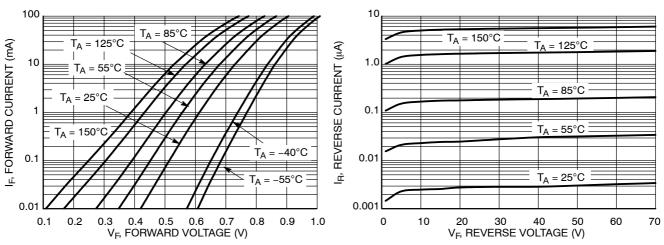


Figure 2. Forward Voltage

Figure 3. Leakage Current

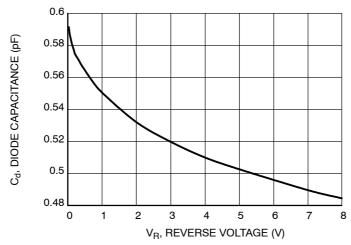
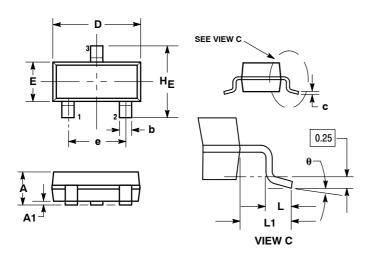


Figure 4. Capacitance

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## PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP** 



#### NOTES

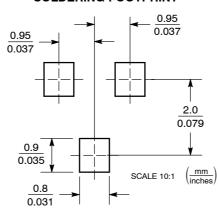
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM 3 THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

#### STYLE 9:

- PIN 1. ANODE
  - ANODE
  - 3 CATHODE

## **SOLDERING FOOTPRINT**



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